Revision: 26-Oct-2021

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1

Vishay General Semiconductor

Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 175 °C capability suitable for high reliability and automotive requirement
- Available in unidirectional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- AEC-Q101 qualified available - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Document Number: 87609

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Peak pulse power dissipation	with 10/1000 µs waveform		3600	144			
	with 10/10 000 µs waveform	P _{PPM}	2800	W			
Power dissipation on infinite heats	PD	5.0	W				
Peak pulse current with 10/1000 µ	I _{PPM} ⁽¹⁾	See next table	А				
Peak forward surge current 8.3 m	I _{FSM}	500	A				
Operating junction and storage te	T _J , T _{STG}	-55 to +175	°C				

Note

 $^{(1)}$ Non-repetitive current pulse at T_A = 25 $^\circ C$



Anode O Cathode

10 V to 43 V

11.1 V to 52.8 V

3600 W

2800 W

5 W

500 A

175 °C

Unidirectional

DO-218AC

PRIMARY CHARACTERISTICS

V_{WM}

 V_{BR}

P_{PPM} (10 x 1000 µs)

P_{PPM} (10 x 10 000 µs)

 P_D

IFSM

T_{.1} max.

Polarity

Package



SM5S10AT thru SM5S43AT



www.vishay.com

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
DEVICE	BREAKDOWN VOLTAGE V _{BR} (V)			TEST CURRENT	STAND-OFF VOLTAGE	MAXIMUM REVERSE LEAKAGE	MAXIMUM REVERSE LEAKAGE	MAX. PEAK PULSE CURRENT	MAXIMUM CLAMPING VOLTAGE	TYPICAL TEMP. COEFFICIENT
TYPE	MIN.	NOM.	MAX.	I _T (mA)	V _{WM} (V)	ΑΤ V _{WM} Ι _D (μΑ)	AT V _{WM} AI V _{WM}	AT 10/1000 µs WAVEFORM (A)	AT I _{PPM} V _C (V)	OF V _{BR} ⁽¹⁾ αΤ (%/°C)
SM5S10AT	11.1	11.7	12.3	5.0	10.0	15	250	212	17.0	0.069
SM5S11AT	12.2	12.9	13.5	5.0	11.0	10	150	198	18.2	0.072
SM5S12AT	13.3	14.0	14.7	5.0	12.0	10	150	181	19.9	0.074
SM5S13AT	14.4	15.2	15.9	5.0	13.0	10	150	167	21.5	0.076
SM5S14AT	15.6	16.4	17.2	5.0	14.0	10	150	155	23.2	0.078
SM5S15AT	16.7	17.6	18.5	5.0	15.0	10	150	148	24.4	0.080
SM5S16AT	17.8	18.8	19.7	5.0	16.0	10	150	138	26.0	0.081
SM5S17AT	18.9	19.9	20.9	5.0	17.0	10	150	130	27.6	0.082
SM5S18AT	20.0	21.1	22.1	5.0	18.0	10	150	123	29.2	0.083
SM5S20AT	22.2	23.4	24.5	5.0	20.0	10	150	111	32.4	0.085
SM5S22AT	24.4	25.7	26.9	5.0	22.0	10	150	101	35.5	0.086
SM5S24AT	26.7	28.1	29.5	5.0	24.0	10	150	93	38.9	0.087
SM5S26AT	28.9	30.4	31.9	5.0	26.0	10	150	86	42.1	0.088
SM5S28AT	31.1	32.8	34.4	5.0	28.0	10	150	79	45.4	0.089
SM5S30AT	33.3	35.1	36.8	5.0	30.0	10	150	74	48.4	0.090
SM5S33AT	36.7	38.7	40.6	5.0	33.0	10	150	68	53.3	0.091
SM5S36AT	40.0	42.1	44.2	5.0	36.0	10	150	62	58.1	0.091
SM5S40AT	44.4	46.8	49.1	5.0	40.0	10	150	56	64.5	0.092
SM5S43AT	47.8	50.3	52.8	5.0	43.0	10	150	52	69.4	0.093

Notes

For all types maximum V_F = 2.0 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses
per minute maximum

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance, junction to case	R _{θJC}	1.0	°C/W		

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SM5S10ATHE3/I ⁽¹⁾	2.505	Ι	750	13" diameter plastic tape and reel, anode towards the sprocket hole		

Note

(1) AEC-Q101 qualified



SM5S10AT thru SM5S43AT

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

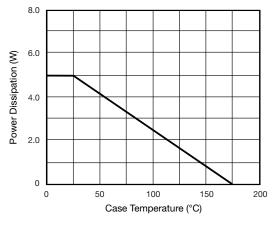


Fig. 1 - Power Derating Curve

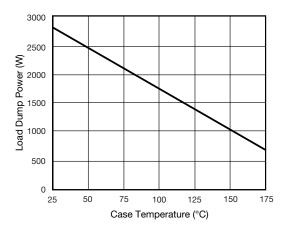


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

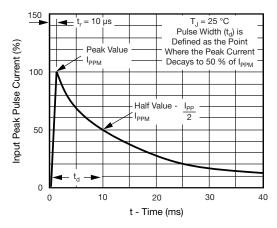


Fig. 3 - Pulse Waveform

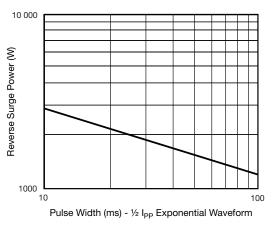


Fig. 4 - Reverse Power Capability

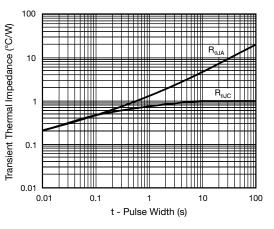


Fig. 5 - Typical Transient Thermal Impedance

Revision: 26-Oct-2021

3

Document Number: 87609

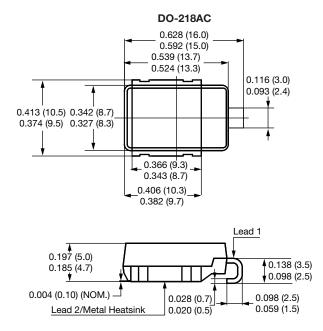
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

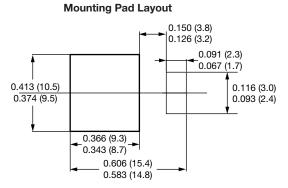


SM5S10AT thru SM5S43AT

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)